# Class C Power Amplifier

**Muhammad Adeel** 

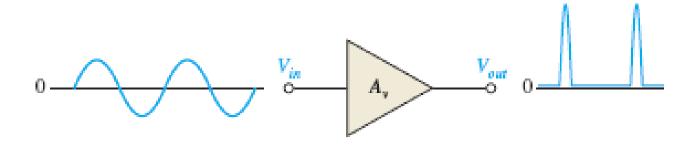
M.Sc. Electronics (KU)

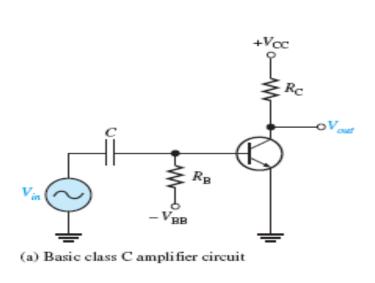
M.Phil. ISPA (KU)

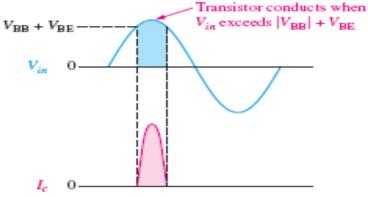
## **Class C Power Amplifier**

Class C amplifiers are biased so that conduction occurs for much less than  $180^{\circ}$  .

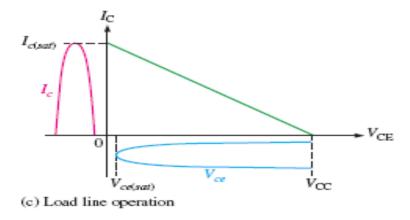
**Class C** amplifiers are more efficient than either class A or push-pull class B and class AB, which means that more output power can be obtained from class C operation.







(b) Input voltage and output current waveforms



The ac source voltage has a peak value that is slightly greater than  $|V_{\rm BE}| + V_{\rm BE}$  so that the base voltage exceeds the barrier potential of the base-emitter junction for a short time near the positive peak of each cycle, during this short interval, the transistor is turned on.

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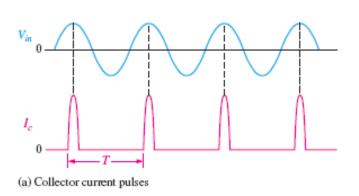
#### **Power Dissipation**

The power dissipation during the *on time is*,

$$P_{D(on)} = I_{c(sat)}V_{ce(sat)}$$

The transistor is on for a short time,  $t_{on}$ , and off for the rest of the input cycle. Therefore, assuming the entire load line is used, the power dissipation averaged over the entire cycle is,

$$P_{\text{D(avg)}} = \left(\frac{t_{\text{on}}}{T}\right) P_{\text{D(on)}} = \left(\frac{t_{\text{on}}}{T}\right) I_{c(sat)} V_{ce(sat)}$$





### **Example**

A class C amplifier is driven by a 200 kHz signal. The transistor is on for 1  $\mu$ s, and the amplifier is operating over 100 percent of its load line. If  $I_{c(sat)} = 100$  mA and  $V_{ce(sat)} = 0.2$  V, what is the average power dissipation of the transistor?

The period is

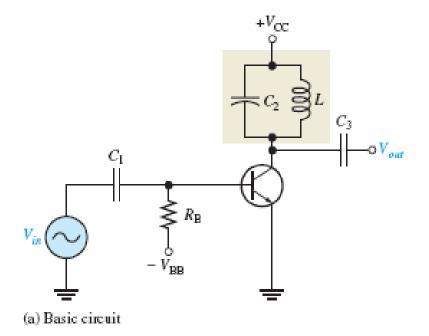
$$T = \frac{1}{200 \,\mathrm{kHz}} = 5 \,\mu\mathrm{s}$$

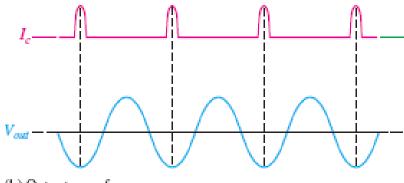
Therefore,

$$P_{\text{D(avg)}} = \left(\frac{t_{\text{on}}}{T}\right) I_{c(sat)} V_{ce(sat)} = (0.2)(100 \text{ mA})(0.2 \text{ V}) = 4 \text{ mW}$$

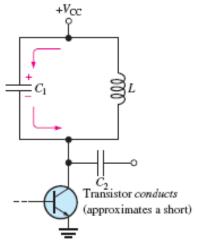
The low power dissipation of the transistor operated in class C is important because, as you will see later, it leads to a very high efficiency when it is operated as a tuned class C amplifier in which relatively high power is achieved in the resonant circuit.

## **Tuned Operation**

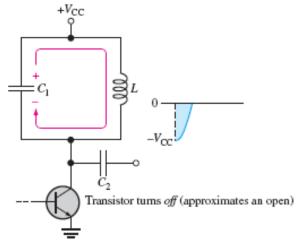




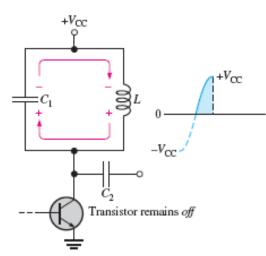
(b) Output waveforms



 (a) C<sub>1</sub> charges to +V<sub>CC</sub> at the input peak when transistor is conducting.

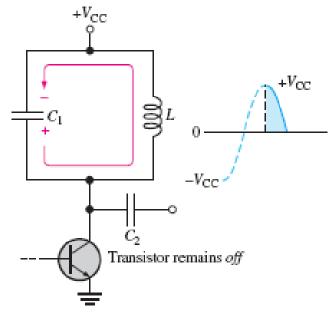


(b) C1 discharges to 0 volts.

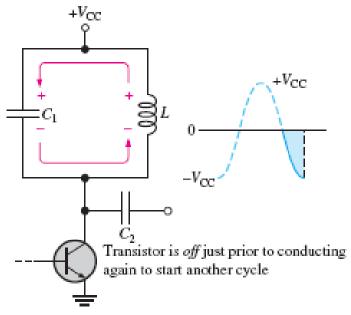


(c) L recharges C1 in opposite direction.

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(d)  $C_1$  discharges to 0 volts.



(e) L recharges  $C_1$ .

### **Maximum output Power and Efficiency**

Since the voltage developed across the tank circuit has a peak-to-peak value of approximately  $2V_{CC}$ , the maximum output power can be expressed as

$$P_{out} = \frac{V_{rms}^2}{R_c} = \frac{(0.707V_{CC})^2}{R_c}$$

$$P_{out} = \frac{0.5V_{CC}^2}{R_c}$$

 $R_c$  is the equivalent parallel resistance of the collector tank circuit at resonance and represents the parallel combination of the coil resistance and the load resistance. It usually has a low value. The total power that must be supplied to the amplifier is

$$P_{\rm T} = P_{out} + P_{\rm D(avg)}$$

Therefore, the efficiency is

$$\eta = \frac{P_{out}}{P_{out} + P_{D(avg)}}$$

When  $P_{out} >> P_{D(avg)}$ , the class C efficiency closely approaches 1 (100 percent).